On Polarization of a Beam Extracted with a Bent Crystal

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Outline

- Basics of the phenomenon
- Numerical example
- Estimation of a volume reflection capabilities
- Conclusions







Consequences from the definition

A beam,

- extracted by means of a bent crystal, must be polarized by definition
- if an analyzing power is not zero.

Polarization calculation

$$P = \frac{(1+A)^{N} - (1-A)^{N}}{(1+A)^{N} + (1-A)^{N}}$$

Lemma: $\Sigma \theta_i = Crystal Bent \pm \theta_{critical}$



Assumptions

To get a numerical estimation let us assume linear dependence

of an analyzing power on the scattering angle

$$A(t) = A_0 \cdot |t/t_0|^{\frac{1}{2}}$$

for very small $|t| < |t_0| = 10^{-3} (GeV/c)^2$ If we consider the channeling as a sequence of scatterings off the crystal lattice then the result does not depend on the beam trajectory inside the crystal. Polarization depends only on the crystal bent.

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Dependence on the A_o



Dependence on the crystal bent



Remark on a general case

- If the analyzing power dependence on the scattering angle is not linear function then a resulting polarization will depend on a trajectory of the particle inside the crystal.
- Channeling in a crystal occupies the transfer momentum domain at

 $|t| < 10^{-5} (GeV/c)^2$

• No experimental data on the analyzing power exists today in this domain.

Volume reflection



Estimation of volume reflection capabilites



Conclusions

- Bent crystal extraction provides a polarization in the resulted beam (strict).
- With certain assumptions a beam polarization could be measurable
- ... or even big enough for practical needs.
- It is also possible to get a beam polarization using a multi turn volume reflection off a bent crystal.
- Using the volume reflection techniques one can utilize a la RICH polarimeter to make measurements.
- Since there is no experimental data today the measurements of a beam polarization provides a tool for a physics in |t| < 10⁻⁵ (GeV/c)² domain which is hardly, if not at all, attainable with the other methods.

Analyzing power at small |t|

Excerpt from talk by A. Bravar (BNL) at Spin05

$$A_N = C_1 \phi_{flip}^{em} * \phi_{non-flip}^{had} + C_2 \phi_{flip}^{had} * \phi_{non-flip}^{had}$$

In absence of hadronic spin – flip contributions A_N is exactly calculable (Lapidus & Kopeliovich):

$$A_N = \sqrt{\frac{8\pi Z\alpha}{m_p^2 \sigma_{tot}^{pA}}} \frac{y^{3/2}}{1+y^2} (\mu - 1) \qquad y = \frac{\sigma_{tot}^{pA} t}{8\pi Z\alpha}$$

For very small $|t| A_N$ can be approximated by

$$A_N \approx |t|^{\alpha} f(s)$$

where α – depends on helicity of initial and final state particles, *f*(*s*) – is a function of the total energy.

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Analyzing power at small |t|

B.Z. Kopeliovich and T.L. Trueman, hep-ph/0012091



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Analyzing power evolution at small t



Estimation of the net polarization

$$P = \frac{(1+A(t))^{N} - (1-A(t))^{N}}{(1+A(t))^{N} + (1-A(t))^{N}}$$

Critical channeling angle in Si $\theta = 5 \mu rad / p^{\frac{1}{2}} (TeV/c)^{\frac{1}{2}}$ (a) $p = 70 \ GeV/c \implies \theta \approx 20 \mu rad$ 100 mrad bend gives N = 5000If $A(t) = A_0 \cdot |t/t_0|^{\frac{1}{2}}$

for very small $-t < t_0 = 10^{-3} GeV^2$

and $A_0 = A(10^{-3} \text{ GeV}^2) = 0.005$ Then $P \approx 0.8$



Independence on the channeling assumptions



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